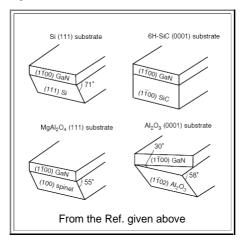
## **Cleaving Semiconductors for (Blue) Lasers Diodes**

- The module is based on the paper of Kuramta et al: in FUJITSU Sci. Tech. J. **342** (1998). p.191. The authors provide data about **cleavage planes in semiconductors**.
  - The preferred cleavage planes of a semiconductor are not as clear-cut as it seems. As everybody know who just once dropped a {100} Si wafer knows, the fracture plans are the {110} planes; a large part of the literature, however, including the paper given above, insists that it should be {111}.
  - Be that as it may, here we take the planes given in the article.

Material	Crystal structure	Effective lattice mismatch (%)	Difference in thermal expansion coefficient (×10-6)	Cleavage	Stability
Si	Diamond	20.1	-2.0	(111)	Good
GaAs	Zinc blende	25.3	0.4	(110)	Fair
GaP	Zinc blende	20.7	-0.9	(110)	Fair
MgO	Rock salt	-6.5	4.9	(100)	Fair
MnO	Rock salt	-1.4		(100)	Bad
CoO	Rock salt	-5.4		(100)	Bad
NiO	Rock salt	-7.6		(100)	Bad
MgAl₂O₄	Spinel	-10.3	1.9	(100)	Good
NdGaO₃	Perovskite	-1.2	1.9		Fair
ZnO	Wurtzite	2.0	-2.7	(1-100)	Fair
				(11-20)	
				(0001)	
6H-SIC	ZnS 6H	-3.4	-1.4	(1-100)	Good
				(11-20)	
				(0001)	
LiAIO <sub>2</sub>	β-NaFeO₂	1.7	1.7	(001)	Fair
LiGaO <sub>2</sub>	β-NaFeO₂	-0.1	1.9	(010)	Fair
Al <sub>2</sub> O <sub>3</sub>	Corundum	-13.8	1.9	(1-102)	Good
LiNbO₃	Ilmenite	-6.7	9.9	(1-102)	Bad
LiTaO₃	Ilmenite	-6.8	10.6	(1-102)	Fair
		From the I	Ref. given above		

- GaN as a semiconductor technology material only comes as a thin layer on a substrate other than GaN since there simply are no usable GaN single crystals
  - As we know, if we grow thin layers with different lattices, we have to watch out for <u>misfit dislocations</u>. It is important to look for substrates with a lattice constant as similar as possible to that of the thin layer to be grown. The table above shows the lattice mismatch of prospective substrates to **GaN** and thus gives a guideline.
- If we want to make a Laser diode form the thin film, we have a few more requirements besides "just" avoiding misfit dislocations as best as we can:
  - The substrate should have a high electrical and thermal conductivity. The first property would make it easier to supply the large current densities we need to operate a Laser diode, the second to remove efficiently the heat generated during operation.
  - The whole stack of substrate and layers should cleave nicely on a well-defined and very flat plane because the two relevant surfaces obtained by cleavage will serve as the mirrors of the <a href="Faby-Perot resonator">Faby-Perot resonator</a> we need for a Laser. Now look at the possible cleavage relations:



Summing up: There is no ideal substrate - you have to find the optimal compromise once more if you wan to make the blue Laser diode.